TOSHIBA 151832

TOSHIBA RECTIFIER SILICON DIFFUSED TYPE

151832

HIGH SPEED RECTIFIER APPLICATIONS (FAST RECOVERY)

 $: I_{F(AV)} = 0.7 \text{ A (Ta} = 50^{\circ}\text{C)}$ Average Forward Current

Repetitive Peak Reverse Voltage : $V_{RRM} = 1800 V$

Reverse Recovery Time : $t_{rr} = 6.0 \, \mu s$

Plastic Mold Type.

MAXIMUM RATINGS

CHARACTERISTICS	SYMBOL	RATING	UNIT	
Repetitive Peak Reverse Voltage	v_{RRM}	1800	V	
Reverse Voltage (DC)	$V_{\mathbf{R}}$	1500	V	
Average Forward Current (Ta = 50°C)	I _{F (AV)}	0.7	A	
Peak One Cycle Surge Forward Current	Inox	60 (50 Hz)	A	
(Non Repetitive)	$I_{ ext{FSM}}$	66 (60 Hz)		
Junction Temperature	T_{j}	$-40 \sim 125$	°C	
Storage Temperature Range	$\mathrm{T_{stg}}$	$-40 \sim 125$	°C	

6.0 Ø0.8 (2) 1. ANODE 2. CATHODE **JEDEC** DO-15 SC-39 **EIAJ** TOSHIBA 3-3B1A

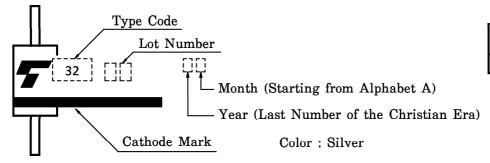
Unit in mm

Weight: 0.42 g

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Peak Forward Voltage	$V_{\mathbf{FM}}$	$I_{\text{FM}} = 1.5 \text{ A}$	_	_	2.0	V
Repetitive Peak Reverse	IRRM (1)	$V_{RRM} = 1500 V$	_	_	10	
Current	I _{RRM} (2)	$V_{RRM} = 1500 \text{ V}, \text{ T}_{j} = 125 ^{\circ}\text{C}$		_	400	μ A
Reverse Recovery Time	t_{rr}	$I_F = 20 \text{ mA}, I_R = 1 \text{ mA}$	_	_	6	μ s

MARKING



CODE	TYPE
32	1S1832

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